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<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  (Use as many sheets as necessary)		Application Number	10/763,733
		Filing Date	Herewith 1/22/2004
		First Named Inventor	Peter John McElheny
		Art Unit	2825
		Examiner Name	PHALLAKA KIK
Sheet 1	of 1	Attorney Docket Number	A1167

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
PJ		RAFIK S. GUINDI ET AL., "Design Techniques for Gate-Leakage Reduction in CMOS Circuits," 2003 IEEE pp. 61-65, 24 March 2003.	
PJ		VIJAYKRISHNAN NARAYANAN, "Managing Leakage: From Circuits to Software" <a href="http://www.cse.psu.edu/~mdl">http://www.cse.psu.edu/~mdl</a> , Comp. Architecture Seminar, UT Austin 2/18/02, pp. 1-68.	
PJ		"Part II Leakage Reduction Techniques", ICCAD 2002 Tutorial; pp 1-50.	
PJ		AFSHIN ABDOLLAHI ET AL., "Runtime Mechanisms for Leakage Current Reduction in CMOS VSLI Circuits", ISLPED' 02, August 12-14, 2002, pp. 1-6.	
PJ		JAMES KAO ET AL. "Transistor Sizing Issues and Tool for Multi-Threshold CMOS Technology," DAC 97, Anaheim, CA (c) 1997, pp. 1-6.	
PJ		MOHAB ANIS ET AL., "Dynamic and Leakage Power Reduction in MTCMOS Circuits Using an Automated Efficient Gate Clustering Technique" (undated), pp. 1-27.	
PJ		B. NIKOLIC, "Advanced Digital Circuits" EE241 Lecture Notes, Spring 2002, pp. 1-16.	
PJ		FEI LI ET AL. "Maximum Current Estimation Considering Power Gating" <a href="http://eda.ece.wisc.edu">http://eda.ece.wisc.edu</a> (undated); pp. 1-16, University of Wisconsin-Madison.	

Examiner Signature	<i>Phallaka Kik</i>	Date Considered	12/24/05
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.  
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